

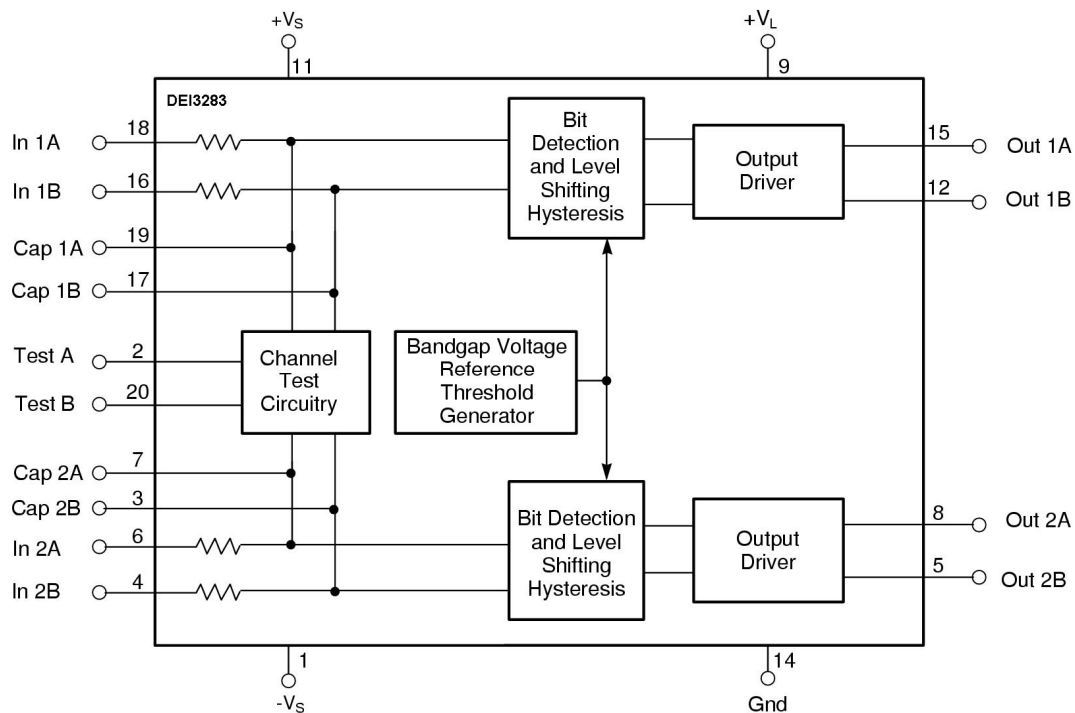
# DEI3283

## DUAL ARINC 429 LINE RECEIVER

### FEATURES

- Two separate analog receiver channels
- Converts ARINC 429 levels to serial data
- ARINC 429 inputs withstand +/-200V
- TTL inputs to test complete analog/digital RX function
- TTL and CMOS compatible outputs
- Low power dissipation
- Internal band gap voltage reference
- MIL-STD-883B burn-in screening available
- Package Options: 20 Lead ceramic DIP, 20 Terminal ceramic LCC, and 20 Lead SOIC
- Direct replacement for Fairchild/Raytheon RM3283 and RM3183 and Holt HI-8482

### Function Diagram



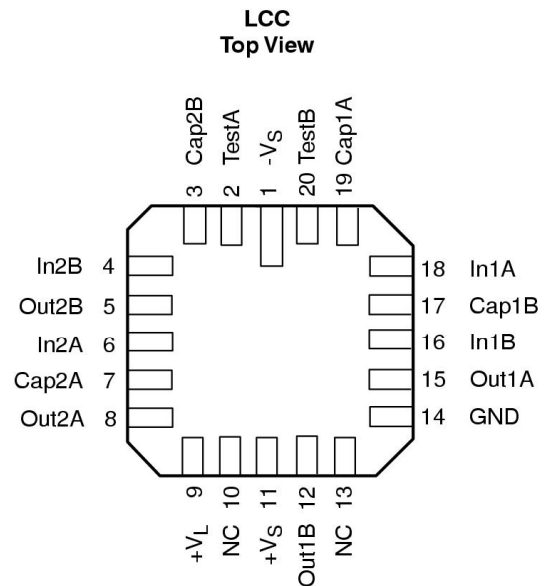
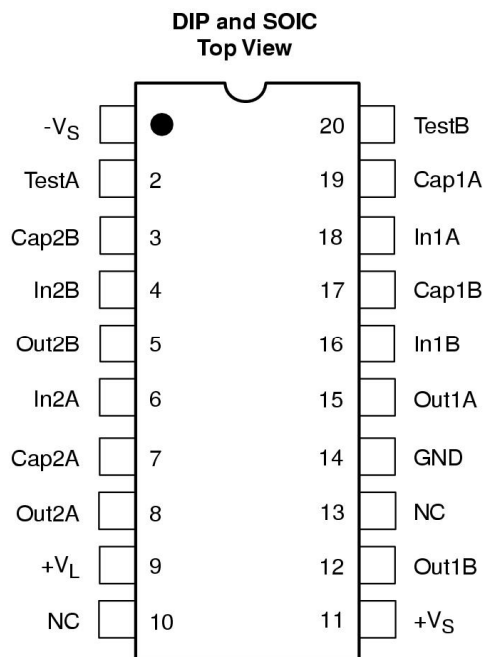
## General Description

The DEI3283 consists of two analog ARINC 429 receivers which take differentially encoded ARINC level data and convert it to serial TTL level data. The DEI3283 provides two complete analog ARINC receivers with no external components required. Input level shifting thin film resistors and bipolar technology allow ARINC input voltage transients up to  $\pm 200V$  without damage to the DEI3283. Each channel is identical, featuring symmetrical propagation delays for better high speed performance. Input common mode rejection is excellent and threshold voltage is stable, independent of supply voltage. Data outputs are TTL and CMOS compatible. Two TTL compatible test inputs used to test the ARINC channels are available. They can be used to override the ARINC input data and set the channel outputs to a known state. The DEI ARINC line driver family IC's are companion chips to the DEI3283 line receiver. Together they provide the analog functions needed for the ARINC 429 interface.

## Functional Description

The DEI3283 contains two discrete ARINC 429 receiver channels. Each channel contains three main sections: a resistor input network, a window comparator, and a logic output buffer stage. The first stage provides over voltage protection and biases the signal using voltage dividers and current sources, providing excellent input common mode rejection. The test inputs are provided to set the outputs to a predetermined state for built-in channel test capability. If the test inputs are not used, they should be grounded. The window comparator section detects data from the resistor input network. A LOGIC 1 corresponds to ARINC "High" state (OUTA) and a LOGIC 0, to ARINC "Low" state (OUTB). An ARINC "Null" state at the inputs forces both outputs to LOGIC 0. Threshold and hysteresis voltages are generated by a band gap voltage reference to maintain stable switching characteristics over temperature and power supply variations. The output stage generates a TTL compatible logic output capable of driving 3mA of load.

## Pin Assignments



PIN	NAME	DESCRIPTION
1	-Vs	Supply Voltage (-15V)
2	TEST A	Logic Input, see functional characteristics.
3	CAP2B	A429 INPUT, Ch 2, B Capacitor node
4	IN2B	A429 INPUT, Ch 2, B input
5	OUT2B	Logic Output, Ch 2, B's output
6	IN2A	A429 INPUT, Ch 2, A input
7	CAP2A	A429 INPUT, Ch 2, A Capacitor node

PIN	NAME	DESCRIPTION
8	OUT2A	Logic Output, Ch 2, A's output
9	+VL	Supply Voltage (+5V)
10	NC	
11	+VS	Supply Voltage (+15V)
12	OUT1B	Logic Output, Ch 1, B's output
13	NC	
14	GND	Supply Return
15	OUT1A	Logic Output, Ch 1, A's output
16	IN1B	A429 INPUT, Ch 1, B input
17	CAP1B	A429 INPUT, Ch 1, B Capacitor node
18	IN1A	A429 INPUT, Ch 1, A input
19	CAP1A	A429 INPUT, Ch 1, A Capacitor node
20	TESTB	Logic Input, see functional characteristics.

## Absolute Maximum Ratings

Parameter		Min.	Max.	Units
Supply Voltage:	+VS to -VS		+36	V
	+VS to GND		+20	V
	-Vs to GND	-20		V
+VL Voltage			+7	V
Logic Input Voltage		-0.3	+VL + 0.3	V
ARINC 429 Input Voltage		-200	+200	V
Temperature Range	Storage	-65	+150	°C
	Operating	-55	+125	°C
Junction Temperature	Ceramic	-55	+175	°C
	Plastic	-55	+145	°C
Lead Soldering Temperature (60 sec., DIP, LCC)			+300	°C
Peak Body Temperature, J-STD-020 (SOIC)				
Non-G Package			+240	°C
-G Package			+260	°C

## Recommended Operating Conditions

Symbol	Parameters	Min.	Max.	Units
+Vs	Positive Supply Voltage	13.5	16.5	V
-Vs	Negative Supply Voltage	-16.5	-13.5	V
+VL	+VL Supply Voltage	4.5	5.5	V
T <sub>op</sub>	Case Temperature			
	Ceramic	-55	+125	°C
	Plastic: -SA	-40	+125	°C
	-SE	-55	+85	°C

## Electrical Characteristics

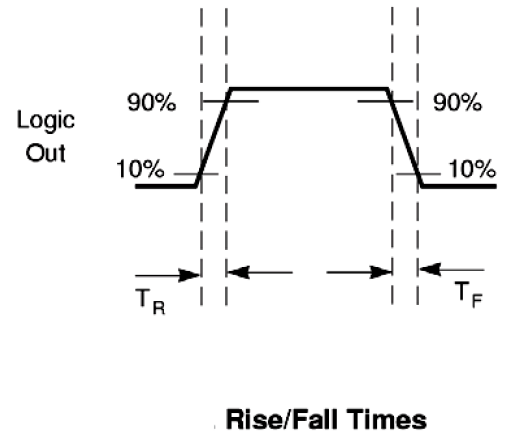
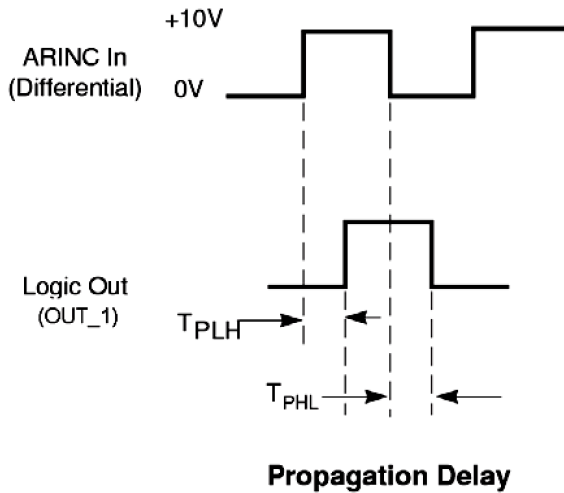
Symbol	Parameter	Conditions (1,2)	Min.	Max.	Units
<b>POWER SUPPLIES</b>					
ICC	+VS (+15V) Supply Current	Supply = +/- 16.5V, VI = 5.0V, Test Inputs = 0V Test Inputs = 5V	3.5 3.5	6.0 6.0	mA
IEE	-Vs (-15V) Supply Current	Supply = +/- 16.5V, VI = 5.0V, Test Inputs = 0V Test Inputs = 5V	7.5 11.0	12.0 18.5	mA
IL	+VL (+5V) Supply Current	Supply = +/- 16.5V, VI = 5.0V, Test Inputs = 0V Test Inputs = 5V	4.5 10.8	9.0 17.6	mA
<b>A429 INPUTS</b>					
VHH	NULL to 1 transition, V(INA) – V(INB)	Supply = +/-15.0V, VI = 5.00V Test inputs = 0V VINB = -2.50V	5.70	6.30	V
VHL	1 to NULL transition, V(INA) – V(INB)	Supply = +/-15.0V, VI = 5.00V Test inputs = 0V VINB = -2.50V	4.50	5.50	V
VHHYS	1 to NULL transition hysteresis	VHH-VHL	0.8	1.2	V
VLL	NULL to 0 transition, V(INA) – V(INB)	Supply = +/-15.0V, VI = 5.00V Test inputs = 0V VINB = +2.50V	-6.30	-5.70	V
VHL	0 to NULL transition, V(INA) – V(INB)	Supply = +/-15.0V, VI = 5.00V Test inputs = 0V VINB = +2.50V	-5.50	-4.50	V
VLHYS	0 to NULL transition hysteresis	VLL-VLH	-1.2	-0.8	V
VCM	Input common mode voltage range		-13	+13	V
RINGND	Input resistance, Input to GND	Unpowered, INA to GND, INB to GND	20	30	kΩ
RIN	Input resistor, INA to CAPA, INB to CAPB	Unpowered INA to CAPA, INB to CAPB	8.5	11.5	kΩ
CIN	Input capacitance, INA to GND, INB to GND	(3)		10	pF
<b>TEST LOGIC INPUTS</b>					
VIH	LOGIC 1 input voltage	Functional Test	2.0		V
VIL	LOGIC 0 input voltage	Functional Test		0.9	V
IIH	LOGIC 1 input current	VIH = 5V Supply = +/-15.0V, VI = 5.00V	0	600	μA
IIL	LOGIC 0 input current	VIL = 0.8V Supply = +/-15.0V, VI = 5.00V	0	50	μA
<b>LOGIC OUTPUTS</b>					
VOH	LOGIC 1 output voltage	Vsupply = +/-15.0V, VI = 5.0V IOH = -100uA (Room Temp) IOH = -2.8mA	4.0 3.5		V V
VOL	LOGIC 0 output voltage	Vsupply = +/-15.0V, VI = 5.0V IOL = 100uA (Room Temp) IOL = 2.0mA		0.1 0.8	V V

Symbol	Parameter	Conditions (1,2)	Min.	Max.	Units
Tr	Output rise time	CL = 60 pF (4)	10	70	ns
Tf	Output Fall Time	CL = 60 pF (4)	10	70	ns
TPLH	Prop delay, A429 to LH output	A429 In = 0 to 10V (4) CAPA, CAPB, OUT CL = 60 pF		1500	ns
TPHL	Prop delay, A429 to HL output	A429 In = 0 to 10V (4) CAPA, CAPB, OUT CL = 60 pF		1500	ns
DTP	Matching of TPLH and TPHL	TPLH-TPHL  (4)		500	ns
TPTLH	Prop delay, TESTA/B to LH output	CL = 60 pF, VIN = 0.8V/2.0V (4)	400	600	ns
TPTHL	Prop delay, TESTA/B to HL output	CL = 60 pF, VIN = 0.8V/2.0V (4)	800	1300	ns

**Notes:**

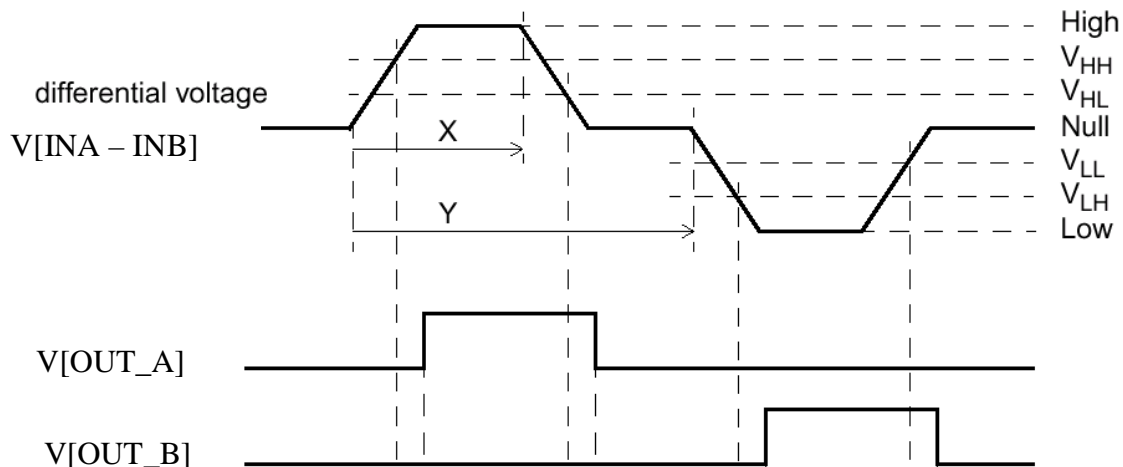
1. Unless otherwise noted, currents flowing in to DUT are positive, Currents flowing out of DUT are negative, Voltages are referenced to Ground.
2. Unless otherwise noted, Tcase = -55°C to +125°C for -xMx, -40°C to +125°C for -xAx, and -55°C to +85°C for -xEx versions; +VS = +13.5 to 16.5V, -Vs = -13.5 to -16.5V, +VL = 4.5 to 5.5V.
3. Guaranteed by design. Not production tested.
4. Sample tested.

**AC Test Waveforms**



## Functional Characteristics

ARINC Inputs V(A) – V(B)	Test Inputs		Outputs		Output State
	TEST A	TEST B	OUT_A	OUT_B	
Null	0	0	0	0	Null
Low	0	0	0	1	Low
High	0	0	1	0	High
X	0	1	0	1	Low
X	1	0	1	0	High
X	1	1	0	0	Null



Parameter	Characteristics (100KBS)		
	min	max	units
Time Y	9.75	10.25	us
Time X	4.87	5.13	us
Pulse rise time	0.5	2	us
Pulse fall time	0.5	2	us
Vhigh	+7.25	11	V diff
Vhh		+6.5	V diff
Vhl	+2.5		V diff
Vnull	-0.5	+0.5	V diff
Vll		-2.5	V diff
Vlh	-6.5		V diff
Vlow	-11	-7.25	V diff

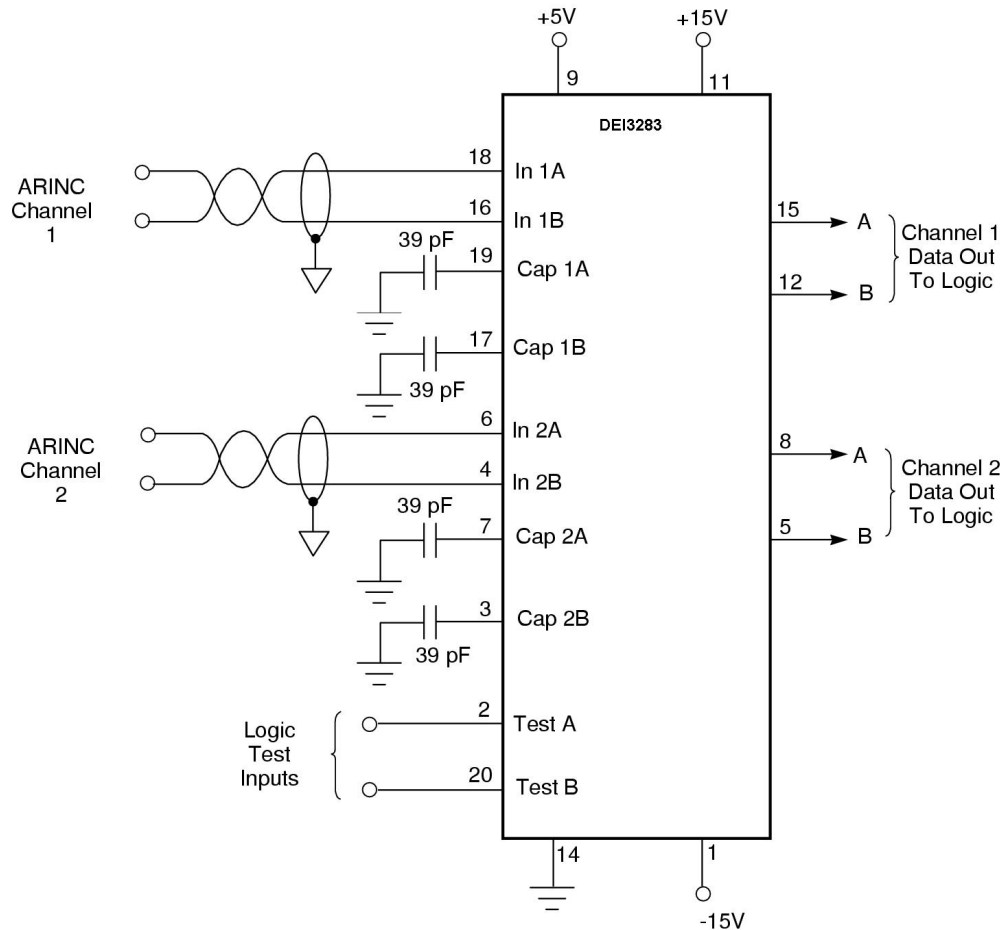
## Applications Discussion

The standard connections for the DEI3283 are shown in the figure below. Dual  $\pm 15\text{VDC}$  supplies are recommended for the +VS/-VS supplies. Decoupling of all supplies should be done near the IC to avoid propagation of noise spikes due to switching transients. The ground connection should be sturdy and isolated from large switching currents to provide as quiet a ground reference as possible. The noise filter capacitors are optional and are added to provide extra noise immunity by limiting bandwidth of the input signal before it reaches the window comparator stage. Two capacitors are used for each channel and they must be the same value. The suggested capacitor value for a 100 kHz operation is 39 pF. For lower data rates, larger values of capacitance may be used to yield better noise performance. To get optimum performance, the following equation can be used to calculate capacitor value for a specific data rate:

$$C_{\text{FILTER}} = \frac{3.95 \times 10^{-6}}{F_O}$$

Where  $C_{\text{FILTER}}$  is the capacitor value in pF, and  $F_O$  is the input frequency ( $10 \text{ kHz} \leq F_O \leq 150 \text{ kHz}$ ).

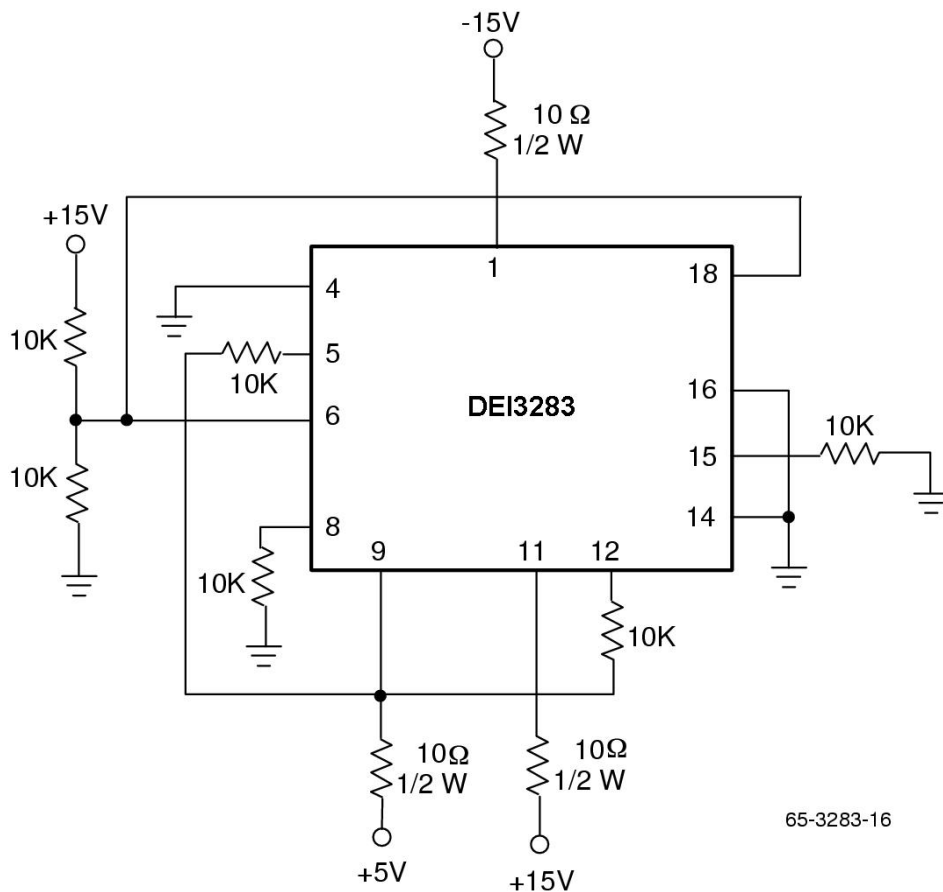
## Applications



ARINC Receiver Standard Connections

## Process Flow

Process Step	Plastic Standard	Ceramic Standard	Plastic Burn-In	Ceramic Burn-In
THERMAL CYCLE MIL-STD-883B M1010.4 Condition B	NO	10 Cycles	NO	10 Cycles
CONSTANT ACCELERATION MIL-STD-883B M2001, Method D.	N/A	YES	N/A	YES
GROSS & FINE LEAK MIL-STD-883B M1014.10	N/A	YES	N/A	YES
PRE-BURN-IN Electrical Test	N/A	N/A	YES	YES
BURN IN MIL-STD-883B M1015 Condition A	N/A	N/A	160hrs @ +125 °C	160hrs @ +125 °C
FINAL ELECTRICAL TEST, Room Temperature	100%	100%	100%	100%
FINAL ELECTRICAL TEST, High Temperature	100% @ +85 or +125°C	100% @ +125°C	100% @ +85 or +125°C	100% @ +125°C
FINAL ELECTRICAL TEST, Low Temperature	0.65% AQL @ -55 or -40°C	0.65% AQL @ -55°C	0.65% AQL @ -55 or -40°C	0.65% AQL @ -55°C



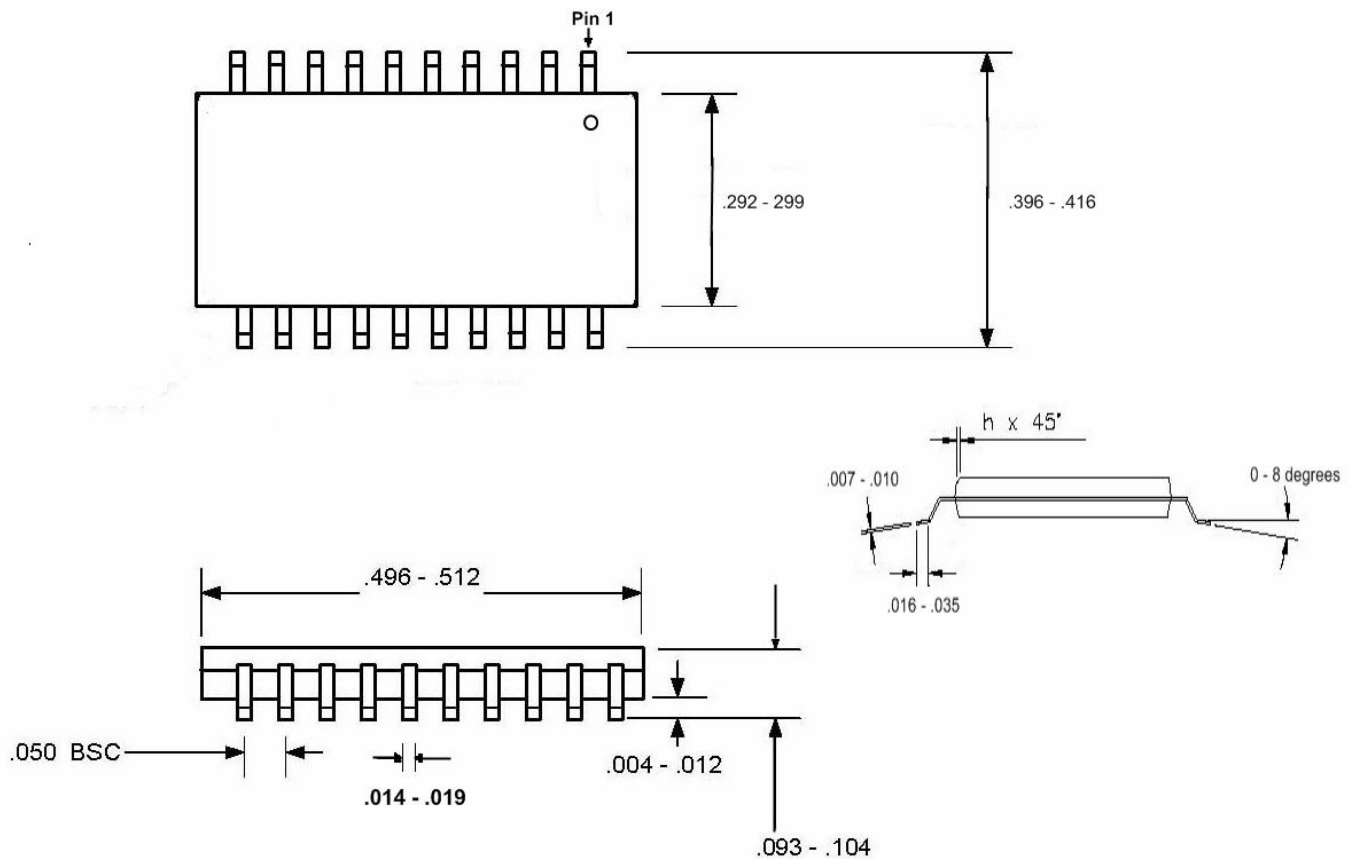
Burn-In Circuit



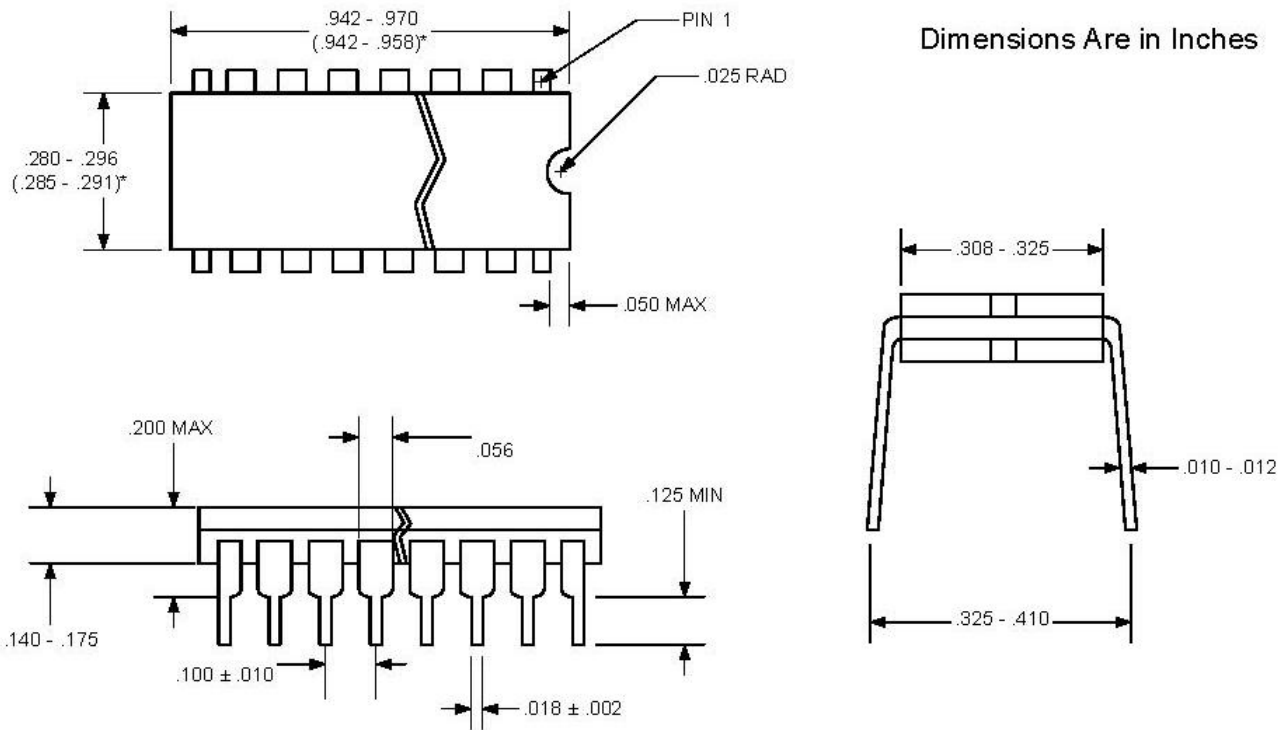
## Package Characteristics

Package Characteristics					
PACKAGE TYPE	20L Ceramic LCC	20L CERDIP	20L CERDIP GREEN	20L SOIC	20L SOIC GREEN
Reference (see ordering info)	20 CLCC	20 CERDIP	20 CERDIP G	20 SOIC	20 SOIC G
JEDEC MO Reference	MO-047	MS-030-A-AE	MS-030-A-AE	MS-013-AE	MS-013-AE
THERMAL RESISTANCE: $\theta_{JA}$ (4 layer PCB) $\theta_{JC}$	85 °C/W 30 °C/W	70 °C/W 28 °C/W	70 °C/W 28 °C/W	85 °C/W 30 °C/W	85 °C/W 30 °C/W
JEDEC Moisture Sensitivity Level (MSL)	Hermetic	Hermetic	Hermetic	MSL 1 / 250°C	MSL 1 / 250°C
Lead Finish Material / JEDEC Pb-free code	SnPb solder dip na	SnPb solder dip na	SnAgCu solder dip e1	SnPb plate na	Matte Sn e3
Pb-Free DESIGNATION	Not Pb-free	Not Pb-free	Pb free	Not Pb-free	RoHS Compliant

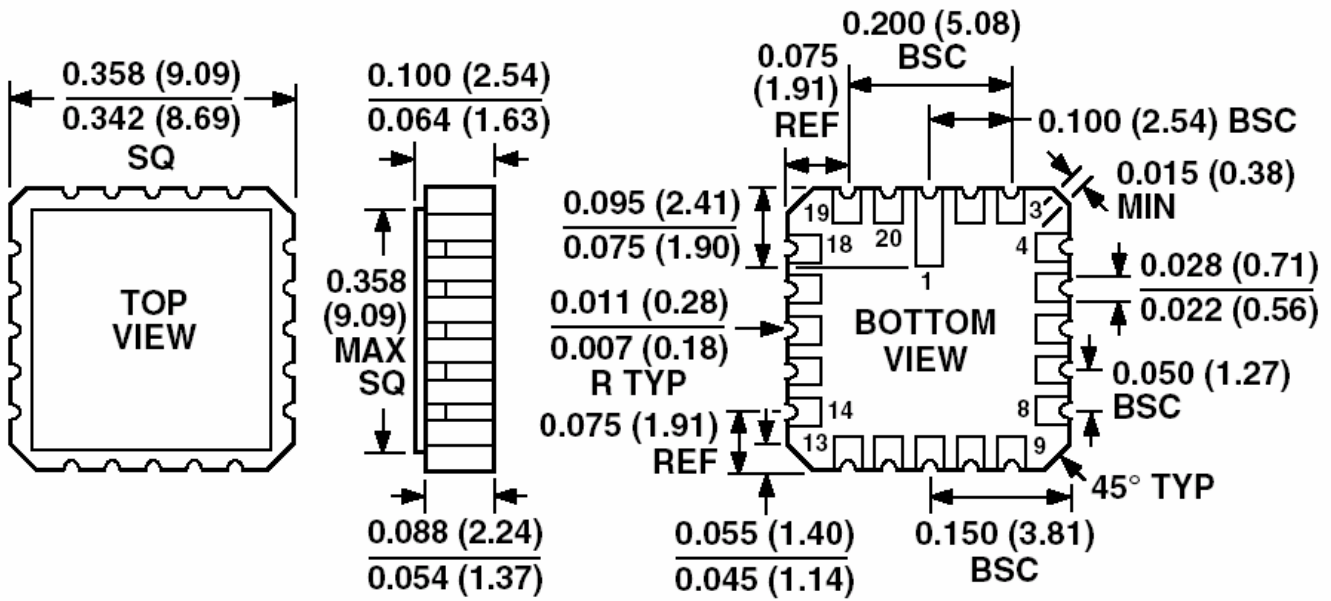
### 20L SOIC ( – G and non - G ) Package



### 20L CERDIP (-G and non-G) Package



### 20L Ceramic LCC Package



## Ordering Information

Part Number	Marking	Package	Operating Temperature Range	Burn In
DEI3283-CMB	DEI3283-CMB	20 CERDIP	-55°C to +125°C	Y
DEI3283-CMB-G	DEI3283-CMB E1	20 CERDIP G	-55°C to +125°C	Y
DEI3283-CMS	DEI3283-CMS	20 CERDIP	-55°C to +125°C	N
DEI3283-CMS-G	DEI3283-CMS E1	20 CERDIP G	-55°C to +125°C	N
DEI3283-EMB	DEI3283-EMB	20 CLCC	-55°C to +125°C	Y
DEI3283-EMS	DEI3283-EMS	20 CLCC	-55°C to +125°C	N
DEI3283-SAB	DEI3283-SAB	20 SOIC	-40°C to +125°C	Y
DEI3283-SAB-G	DEI3283-SAB E3	20 SOIC G	-40°C to +125°C	Y
DEI3283-SAS	DEI3283-SAS	20 SOIC	-40°C to +125°C	N
DEI3283-SAS-G	DEI3283-SAS E3	20 SOIC G	-40°C to +125°C	N
DEI3283-SEB	DEI3283-SEB	20 SOIC	-55°C to +85°C	Y
DEI3283-SEB-G	DEI3283-SEB E3	20 SOIC G	-55°C to +85°C	Y
DEI3283-SES	DEI3283-SES	20 SOIC	-55°C to +85°C	N
DEI3283-SES-G	DEI3283-SES E3	20 SOIC G	-55°C to +85°C	N
DEI3283-SMB	DEI3283-SMB	20 SOIC	-55°C to +125°C	Y
DEI3283-SMB-G	DEI3283-SMB E3	20 SOIC G	-55°C to +125°C	Y
DEI3283-SMS	DEI3283-SMS	20 SOIC	-55°C to +125°C	N
DEI3283-SMS-G	DEI3283-SMS E3	20 SOIC G	-55°C to +125°C	N

Notes:

1. All packages marked with Lot Code and Date Code. "E1" or "E3" after Date Code denotes Pb Free category.
2. The -CMB/-EMB/-SAB/-SEB/-SMB parts may be marked as -CMS/-EMS/-SAS/-SES/-SMS with a "B" stamp to denote burn-in.

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